



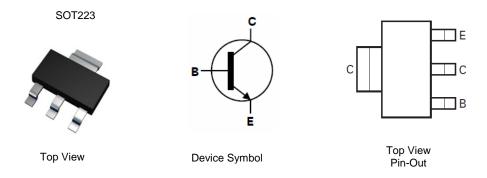
25V NPN HIGH PERFORMANCE TRANSISTOR IN SOT223

Features

- BV_{CEO} > 25V
- I_C = 3A High Continuous Current
- I_{CM} = 8A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 300mV @ 1A
- Complementary PNP Type: FZT749
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.112 grams (Approximate)



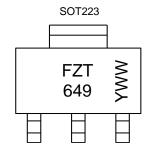
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT649TA	Standard	FZT649	7	12	1,000
FZT649TC	Standard	FZT649	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



FZT649 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	35	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	3	Α
Peak Pulse Current	I _{CM}	8	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	2	W
Fower Dissipation	(Note 6)	- P _D	3	W
Thermal Decistores, Junction to Ambient	(Note 5)	_	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	− R _{θJA}	41.7	°C/W
Thermal Resistance, Junction to Leads (Note	$R_{\theta JL}$	12.9	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

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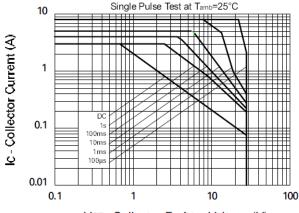
Notes:

- 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 6. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

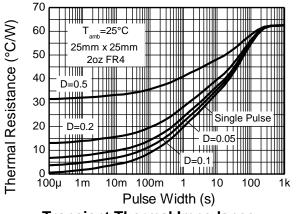


Thermal Characteristics and Derating Information

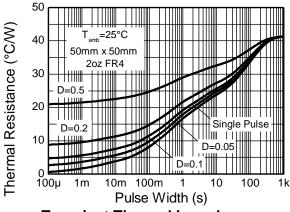


VCE - Collector Emitter Voltage (V)

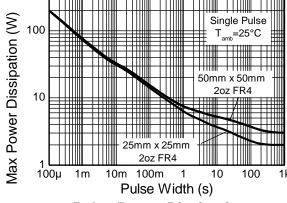
Safe Operating Area



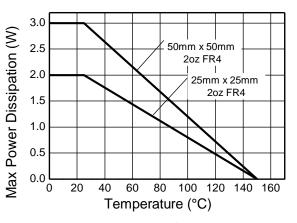




Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve



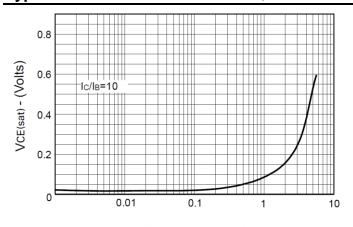
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	35	-	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	25	-	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	-	-	V	$I_E = 100\mu A$
Collector Cut-Off Current	,	-	-	0.1	μΑ	$V_{CB} = 30V$
Collector Cut-Oil Current	I _{CBO}	-	-	10		$V_{CB} = 30V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}	-	-	100	nA	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage (Note 9)	\/·	-	0.12	0.3	V	$I_C = 1A$, $I_B = 100mA$
Collector-Entitler Saturation Voltage (Note 9)	V _{CE(sat)}	-	0.40	0.6	V	$I_C = 3A$, $I_B = 300mA$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	0.9	1.25	V	$I_C = 1A$, $I_B = 100mA$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	-	0.8	1.0	V	$I_C = 1A$, $V_{CE} = 2V$
	h _{FE}	70	200	-		$I_C = 50 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Gain (Note 9)		100	200	300		$I_C = 1A$, $V_{CE} = 2V$
DC Current Gain (Note 9)		75	150	-	_	$I_C = 2A$, $V_{CE} = 2V$
		15	50	_		$I_C = 6A, V_{CE} = 2V$
Current Gain-Bandwidth Product	f⊤	150	240	=	MHz	$V_{CE} = 5V, I_{C} = 100mA,$ f = 100MHz
Switching Times	t _{on}	-	55	-	ns	$I_C = 500 \text{mA}, V_{CC} = 10 \text{V},$
Switching filles	t _{off}	-	300	-	115	$I_{B1} = -I_{B2} = 50 \text{mA}$
Output Capacitance	C _{obo}	-	25	50	pF	$V_{CB} = 10V$, $f = 1MHz$

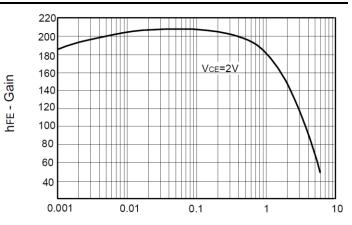
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

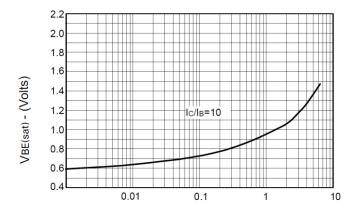


Ic - Collector Current (Amps)



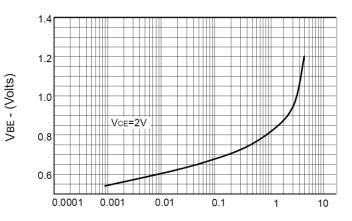
Ic - Collector Current (Amps)

VCE(sat) v IC



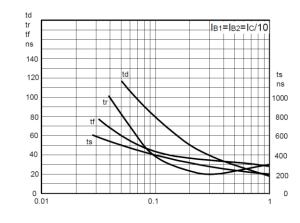
Ic - Collector Current (Amps)

hfe v IC



Ic - Collector Current (Amps)

VBE(sat) v IC



Ic - Collector Current (Amps)

Switching Speeds

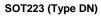
VBE(on) v IC

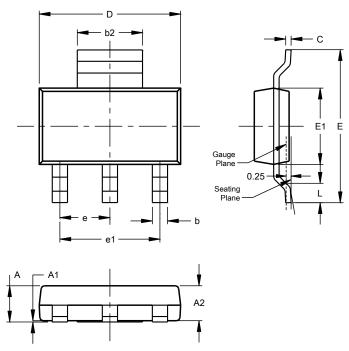
Switching time



Package Outline Dimensions

Please see https://www.diodes.com/design/support/packaging/ for the latest version.



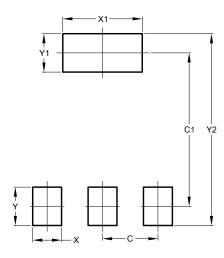


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
Ь	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see https://www.diodes.com/design/support/packaging/ for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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